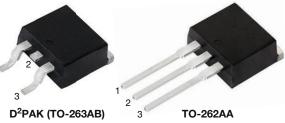
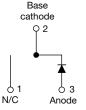
SHAY www.vishay.com

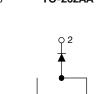
# VS-HFA15TB60S-M3, VS-HFA15TB60-1-M3

**Vishay Semiconductors** 

# HEXFRED<sup>®</sup>, **Ultrafast Soft Recovery Diode, 15 A**







**01** 

N/C

VS-HFA15 TB60S-M3

Anode VS-HFA15 TB60-1-M3

3

PRIMARY CHARACTERISTICS								
I <sub>F(AV)</sub> 15 A								
V <sub>R</sub>	600 V							
V <sub>F</sub> at I <sub>F</sub>	1.2 V							
t <sub>rr</sub> (typ.)	23 ns							
T <sub>J</sub> max.	150 °C							
Package	D <sup>2</sup> PAK (TO-263AB), TO-262AA							
Circuit configuration	Single							

## **FEATURES**

- · Ultrafast and ultrasoft recovery
- Very low I<sub>BBM</sub> and Q<sub>rr</sub>
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C
- Designed and gualified for industrial level
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

## BENEFITS

- Reduced RFI and EMI
- · Reduced power loss in diode and switching transistor
- Higher frequency operation
- Reduced snubbing
- Reduced parts count

## DESCRIPTION

VS-HFA15TB60S, VS-HFA15TB60-1 is a state of the art ultrafast recovery diode. Employing the latest in epitaxial construction and advanced processing techniques it features a superb combination of characteristics which result in performance which is unsurpassed by any rectifier previously available. With basic ratings of 600 V and 15 A continuous current, the VS-HFA15TB60S, VS-HFA15TB60-1 is especially well suited for use as the companion diode for IGBTs and MOSFETs. In addition to ultrafast recovery time, the HEXFRED® product line features extremely low values of peak recovery current (I<sub>RBM</sub>) and does not exhibit any tendency to "snap-off" during the tb portion of recovery. The HEXFRED features combine to offer designers a rectifier with lower noise and significantly lower switching losses in both the diode and the switching transistor. These HEXFRED advantages can help to significantly reduce snubbing, component count and heatsink sizes. The HEXFRED VS-HFA15TB60S, VS-HFA15TB60-1 is ideally suited for applications in power supplies and power conversion systems (such as inverters), motor drives, and many other similar applications where high speed, high efficiency is needed.

ABSOLUTE MAXIMUM RATINGS								
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS				
Cathode to anode voltage	V <sub>R</sub>		600	V				
Maximum continuous forward current	I <sub>F</sub>	T <sub>C</sub> = 100 °C	15					
Single pulse forward current	I <sub>FSM</sub>		150	А				
Maximum repetitive forward current	I <sub>FRM</sub>		60					
Maximum nauver dissinction	D	T <sub>C</sub> = 25 °C	74	W				
Maximum power dissipation	PD	T <sub>C</sub> = 100 °C	29	vv				
Operating junction and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		-55 to +150	°C				

Revision: 16-Dec-2021

Document Number: 96313



FREE

For technical questions within your region: DiodesAmericas@vishay.com, DiodesAsia@vishay.com, DiodesEurope@vishay.com THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishav.com/doc?91000



# Vishay Semiconductors

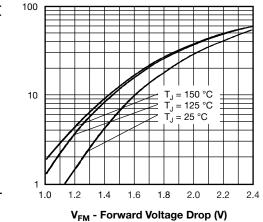
ELECTRICAL SPECIFIC	CATIONS	$(T_J = 25 \ ^{\circ}C \text{ unless otherwise s})$	pecified)				
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
Cathode to anode breakdown voltage	V <sub>BR</sub>	I <sub>R</sub> = 100 μA		600	-	-	
		I <sub>F</sub> = 15 A		-	1.3	1.7	V
Maximum forward voltage	V <sub>FM</sub>	I <sub>F</sub> = 30 A	See fig. 1	-	1.5	2.0	
		I <sub>F</sub> = 15 A, T <sub>J</sub> = 125 °C		-	1.2	1.6	
Maximum reverse		$V_{R} = V_{R}$ rated	See fig. 0	-	1.0	10	
leakage current	I <sub>RM</sub>	$T_J = 125 \text{ °C}, V_R = 0.8 \text{ x } V_R \text{ rated}$	See fig. 2	-	400	1000	μA
Junction capacitance	CT	V <sub>R</sub> = 200 V	See fig. 3	-	25	50	pF
Series inductance	L <sub>S</sub>	Measured lead to lead 5 mm from p	ackage body	-	8.0	-	nH

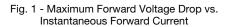
DYNAMIC RECOVERY	CHARAC	<b>TERISTICS</b> ( $T_J = 25$	°C unless otherwis	e specifie	d)		
PARAMETER	SYMBOL	TEST CO	NDITIONS	MIN.	TYP.	MAX.	UNITS
5	t <sub>rr</sub>	$I_F = 1.0 \text{ A}, \text{ d}I_F/\text{d}t = 200 \text{ A}$	Α/μs, V <sub>R</sub> = 30 V	-	23	-	
Reverse recovery time See fig. 5	t <sub>rr1</sub>	T <sub>J</sub> = 25 °C		-	50	60	ns
000 Hg. 0	t <sub>rr2</sub>	T <sub>J</sub> = 125 °C		-	105	120 6.0	
Peak recovery current	I <sub>RRM1</sub>	T <sub>J</sub> = 25 °C		-	4.5	6.0	А
See fig. 6	I <sub>RRM2</sub>	T <sub>J</sub> = 125 °C	I <sub>F</sub> = 15 A	-	6.5	10	A
Reverse recovery charge	Q <sub>rr1</sub>	T <sub>J</sub> = 25 °C	dl <sub>F</sub> /dt = 200 A/µs V <sub>B</sub> = 200 V	-	84	180	nC
See fig. 7	Q <sub>rr2</sub>	T <sub>J</sub> = 125 °C	VR - 200 V	-	241	600	
Peak rate of fall of recovery	dl <sub>(rec)M</sub> /dt1	T <sub>J</sub> = 25 °C		-	188	-	
current during t <sub>b</sub> See fig. 8	dl <sub>(rec)M</sub> /dt2	T <sub>J</sub> = 125 °C		-	160	-	A∕µs

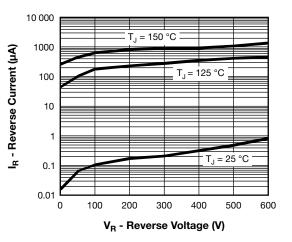
THERMAL - MECHA	NICAL SPEC	CIFICATIONS				
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Lead temperature	T <sub>lead</sub>	0.063" from case (1.6 mm) for 10 s	-	-	300	°C
Thermal resistance, junction-to-case	R <sub>thJC</sub>		-	-	1.7	
Thermal resistance, junction-to-ambient	R <sub>thJA</sub>	Typical socket mount	-	-	80	K/W
Thermal resistance, case-to-heatsink	R <sub>thCS</sub>	Mounting surface, flat, smooth, and greased	-	0.5	-	
Weight			-	2.0	-	g
weight			-	0.07	-	oz.
Marking davias		Case style D <sup>2</sup> PAK (TO-263AB)		HFA15TB60S		
Marking device		Case style TO-262AA		HFA15	TB60-1	

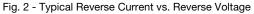


**Vishay Semiconductors** 









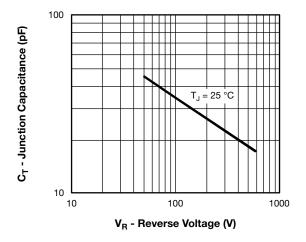
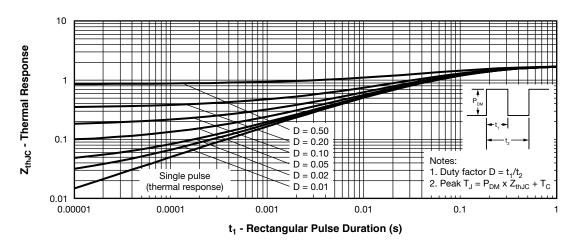


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage





I<sub>F</sub> - Instantaneous Forward Current (A)

VISHAY, www.vishay.com

I<sub>rr</sub> (A)

# VS-HFA15TB60S-M3, VS-HFA15TB60-1-M3

**Vishay Semiconductors** 

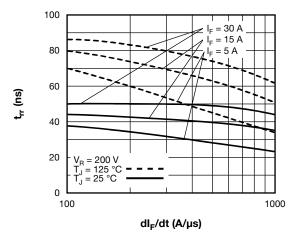


Fig. 5 - Typical Reverse Recovery Time vs. dl<sub>F</sub>/dt

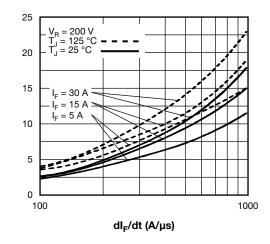


Fig. 6 - Typical Recovery Current vs. dl<sub>F</sub>/dt

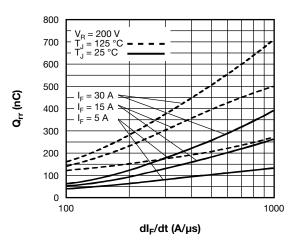


Fig. 7 - Typical Stored Charge vs. dl<sub>F</sub>/dt

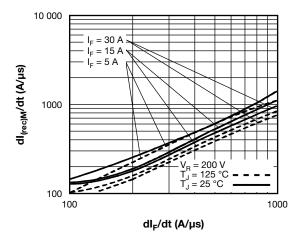


Fig. 8 - Typical dI<sub>(rec)M</sub>/dt vs. dI<sub>F</sub>/dt

Revision: 16-Dec-2021

4

For technical questions within your region: <u>DiodesAmericas@vishay.com</u>, <u>DiodesAsia@vishay.com</u>, <u>DiodesEurope@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>



## **Vishay Semiconductors**

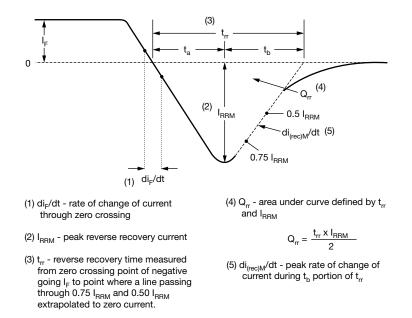


Fig. 9 - Reverse Recovery Waveform and Definitions



**Vishay Semiconductors** 

## **ORDERING INFORMATION TABLE**

Device code	VS-	HF	Α	15	тв	60	S	L	-M3	
		(2)	(3)	(4)	(5)	6	(7)	(8)	(9)	
	<b>1</b> ·	· Visl	nay Sen	niconduo	ctors pro	oduct		0		
	2	- HEX	xFRED <sup>@</sup>	<sup>®</sup> family						
	3	- Ele	ctron irra	adiated						
	4	- Cur	rent rati	ng (15 =	= 15 A)					
	5		kage: = TO-22	20						
	6	- Volt	tage rati	ng (60 =	= 600 V)	)				
	7	• S	= D <sup>2</sup> PA	K (TO-2	63AB)					
	<u> </u>	• • -1	= TO-2	62AA						
	8 -	• N	one = tu	be (50 p	oieces)					
		۰L	= tape a	and reel	(left orie	ented, fo	or D <sup>2</sup> PA	К (ТО-2	263AB)	package)
		• R	= tape a	and reel	(right o	riented,	for D <sup>2</sup> F	PAK (TC	)-263AB	) package
	9 -	M3	s = halog	gen-free	, RoHS-	-complia	ant, and	termina	ations le	ad (Pb)-fr

ORDERING INFORMATION (Example)						
PREFERRED P/N	BASE QUANTITY	PACKAGING DESCRIPTION				
VS-HFA15TB60S-M3	50	Antistatic plastic tube				
VS-HFA15TB60SL-M3	800	13" diameter reel				
VS-HFA15TB60SR-M3	800	13" diameter reel				
VS-HFA15TB60-1-M3	50	Antistatic plastic tube				

LINKS TO RELATED DOCUMENTS							
Dimensions	D <sup>2</sup> PAK (TO-263AB)	www.vishay.com/doc?96164					
Dimensions	TO-262AA	www.vishay.com/doc?96165					
Port marking information	D <sup>2</sup> PAK (TO-263AB)	www.vishay.com/doc?95444					
Part marking information	TO-262AA	www.vishay.com/doc?95443					
Packaging information		www.vishay.com/doc?96424					
SPICE model		www.vishay.com/doc?95357					

**Vishay Semiconductors** 

D<sup>2</sup>PAK

## **DIMENSIONS** in millimeters and inches



ota	ted	90	°C
<u>S</u>	cale	<u>ə:</u> 8	:1

SYMBOL	MILLIM	MILLIMETERS		INCHES		
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES	
Α	4.06	4.83	0.160	0.190		
A1	0.00	0.254	0.000	0.010		
b	0.51	0.99	0.020	0.039		
b1	0.51	0.89	0.020	0.035	4	
b2	1.14	1.78	0.045	0.070		
b3	1.14	1.73	0.045	0.068	4	
с	0.38	0.74	0.015	0.029		
c1	0.38	0.58	0.015	0.023	4	
c2	1.14	1.65	0.045	0.065		
D	8.51	9.65	0.335	0.380	2	

SYMBOL	MILLIM	ETERS	INCHES		NOTES	
	OTMBOE	MIN.	MAX.	MIN.	MAX.	NOTES
	D1	6.86	8.00	0.270	0.315	3
	E	9.65	10.67	0.380	0.420	2, 3
	E1	7.90	8.80	0.311	0.346	3
	е	2.54	2.54 BSC		BSC	
	Н	14.61	15.88	0.575	0.625	
	L	1.78	2.79	0.070	0.110	
	L1	-	1.65	-	0.066	3
	L2	1.27	1.78	0.050	0.070	
	L3	0.25	BSC	0.010	BSC	
	L4	4.78	5.28	0.188	0.208	

### Notes

<sup>(1)</sup> Dimensioning and tolerancing per ASME Y14.5 M-1994

(2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body

(3) Thermal pad contour optional within dimension E, L1, D1 and E1

<sup>(4)</sup> Dimension b1 and c1 apply to base metal only

(5) Datum A and B to be determined at datum plane H

(6) Controlling dimension: inches

<sup>(7)</sup> Outline conforms to JEDEC<sup>®</sup> outline TO-263AB

Revision: 13-Jul-17

1

Document Number: 96164

For technical questions within your region: DiodesAmericas@vishav.com, DiodesAsia@vishav.com, DiodesEurope@vishav.com THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishav.com/doc?91000



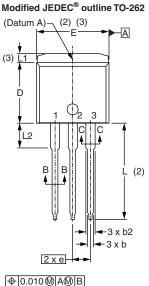
# **Outline Dimensions**

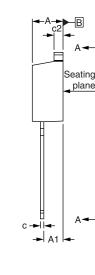


**Vishay Semiconductors** 

**TO-262AA** 

## **DIMENSIONS** in millimeters and inches





F D1 (3) (3) Section A - A Base (4) Plating b1. b3 metal ≰ c1 (4) -(b, b2)-Section B - B and C - C Scale: None





Diodes 1. - Anode (two die)/open (one die) 2., 4. - Cathode 3. - Anode

Lead assignments

CVMPOI	MILLIN	IETERS	INC	HES	NOTES
SYMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.06	4.83	0.160	0.190	
A1	2.03	3.02	0.080	0.119	
b	0.51	0.99	0.020	0.039	
b1	0.51	0.89	0.020	0.035	4
b2	1.14	1.78	0.045	0.070	
b3	1.14	1.73	0.045	0.068	4
С	0.38	0.74	0.015	0.029	
c1	0.38	0.58	0.015	0.023	4
c2	1.14	1.65	0.045	0.065	
D	8.51	9.65	0.335	0.380	2
D1	6.86	8.00	0.270	0.315	3
E	9.65	10.67	0.380	0.420	2, 3
E1	7.90	8.80	0.311	0.346	3
е	2.54	BSC	0.100	) BSC	
L	13.46	14.10	0.530	0.555	
L1	-	1.65	-	0.065	3
L2	3.56	3.71	0.140	0.146	

 <sup>(1)</sup> Dimensioning and tolerancing as per ASME Y14.5M-1994
<sup>(2)</sup> Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the second dimensioner of the second dimensis of the second dimensioner of the second dimensioner of the the outmost extremes of the plastic body (3)

Thermal pad contour optional within dimension E, L1, D1 and E1

<sup>(4)</sup> Dimension b1 and c1 apply to base metal only (5)

Controlling dimension: inches

(6) Outline conform to JEDEC® TO-262 except A1 (max.), b (min., max.), b1 (min.), b2 (max.), c (min.), c1(min.), c2 (max.), D (min.), E (max.), L1 (max.), L2 (min., max.)

Revision: 30-Nov-17

1



Vishay

# Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Hyperlinks included in this datasheet may direct users to third-party websites. These links are provided as a convenience and for informational purposes only. Inclusion of these hyperlinks does not constitute an endorsement or an approval by Vishay of any of the products, services or opinions of the corporation, organization or individual associated with the third-party website. Vishay disclaims any and all liability and bears no responsibility for the accuracy, legality or content of the third-party website or for that of subsequent links.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.